

Vishay High Power Products

# Thyristor/Diode and Thyristor/Thyristor (ADD-A-PAK Generation 5 Power Modules), 105 A



PRODUCT SUMMARY					
I <sub>T(AV)</sub> or I <sub>F(AV)</sub>	105 A				

#### **MECHANICAL DESCRIPTION**

The Generation 5 of ADD-A-PAK modules combine the excellent thermal performance obtained by the usage of Direct Bonded Copper substrate with superior mechanical ruggedness, thanks to the insertion of a solid copper baseplate at the bottom side of the device. The Cu baseplate allows an easier mounting on the majority of heatsink with increased tolerance of surface roughness and improved thermal spread.

The Generation 5 of AAP modules is manufactured without hard mold, eliminating in this way any possible direct stress on the leads.

The electrical terminals are secured against axial pull-out: they are fixed to the module housing via a click-stop feature already tested and proved as reliable on other Vishay HPP modules.

### **FEATURES**

- · High voltage
- Industrial standard package
- · Thick copper baseplate
- UL E78996 approved
- 3500 V<sub>RMS</sub> isolating voltage
- · Totally lead (Pb)-free
- · Designed and qualified for industrial level

#### **BENEFITS**

- Up to 1600 V
- Fully compatible TO-240AA
- · High surge capability
- · Easy mounting on heatsink
- Al<sub>2</sub>0<sub>3</sub> DBC insulator
- · Heatsink grounded

#### **ELECTRICAL DESCRIPTION**

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I <sub>T(AV)</sub> or I <sub>F(AV)</sub>	85 °C	105						
I <sub>O(RMS)</sub>	As AC switch	235	A					
I <sub>TSM,</sub>	50 Hz	1785	A					
I <sub>FSM</sub>	60 Hz	1870						
l <sup>2</sup> t	50 Hz	15.91	kA <sup>2</sup> s					
П	60 Hz	14.52	KA-5					
l <sup>2</sup> √t		159.1	kA²√s					
$V_{RRM}$	Range	400 to 1600	V					
T <sub>Stg</sub>		- 40 to 150	°C					
$T_J$		- 40 to 130	<u> </u>					

### VSK.105..PbF Series

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### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK OFF-STATE VOLTAGE, GATE OPEN CIRCUIT V	I <sub>RRM,</sub> I <sub>DRM</sub> AT 130 °C mA			
	04	400	500	400				
	06	600	700	600				
	08	800	900	800				
VSK.105	10	1000	1100	1000	20			
	12	1200	1300	1200				
	14 1400 1500 1400		1400					
	16	1600	1700	1600				

ON-STATE CONDUCTION						
PARAMETER	SYMBOL		VALUES	UNITS		
Maximum average on-state current (thyristors)	I <sub>T(AV)</sub>	180° conduction	105			
Maximum average forward current (diodes)	I <sub>F(AV)</sub>	T <sub>C</sub> = 85 °C	103			
Maximum continuous RMS on-state current, as AC switch	I <sub>O(RMS)</sub>		or o			
		t = 10 ms	No voltage		1785	Α
		t = 8.3 ms	reapplied	Sinusoidal	1870	
Maximum peak, one-cycle non-repetitive	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>	half wave,	1500	
on-state or forward current	or	t = 8.3 ms	reapplied	initial $T_J = T_J$ maximum	1570	
	I <sub>FSM</sub>	t = 10 ms	T 05.00		2000	
		t = 8.3 ms	$I_J = 25$ °C, no	voltage reapplied	2100	
		t = 10 ms	No voltage		15.91	kA <sup>2</sup> s
	l <sup>2</sup> t	t = 8.3 ms	reapplied	Initial T. T. mayirra	14.52	
Manipular 124 for free a		t = 10 ms	100 % V <sub>RRM</sub>	Initial $T_J = T_J$ maximum	11.25	
Maximum I <sup>2</sup> t for fusing		t = 8.3 ms	reapplied		10.27	
		t = 10 ms	T 05 00 m		20.00	
		t = 8.3 ms	1j = 25 °C, no	voltage reapplied	18.30	
Maximum I <sup>2</sup> √t for fusing	2√t (1)	$t = 0.1 \text{ to } 10 \text{ m}$ $T_J = T_J \text{ maxime}$	159.1	kA²√s		
Maximum value or threshold voltage	V <sub>T(TO)</sub> (2)	Low level (3)	T <sub>J</sub> = T <sub>J</sub> maximum		0.80	٧
waximum value of threshold voltage	<b>V</b> T(TO) (=)	High level (4)	ij = ijillaxili	0.85	V	
Maximum value of on-state	r <sub>t</sub> (2)	Low level (3)	T <sub>J</sub> = T <sub>J</sub> maximum		2.37	mΩ
slope resistance	't \-/	High level (4)			2.25	1115.2
Maximum peak on-state or forward voltage	V <sub>TM</sub>	$I_{TM} = \pi \times I_{T(AV)}$ $I_{FM} = \pi \times I_{F(AV)}$	1.64	٧		
Maximum non-repetitive rate of rise of turned on current	dl/dt	$T_J = 25$ °C, fro $I_{TM} = \pi \times I_{T(AV)}$	150	A/μs		
Maximum holding current	I <sub>H</sub>	T <sub>J</sub> = 25 °C, and resistive load,	250	mA		
Maximum latching current	ΙL	T <sub>J</sub> = 25 °C, and	ode supply = 6	V, resistive load	400	

### Notes

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<sup>(1)</sup>  $I^2t$  for time  $t_x = I^2\sqrt{t} \ x \ \sqrt{t_x}$ 

<sup>(2)</sup> Average power =  $V_{T(TO)} \times I_{T(AV)} + r_t \times (I_{T(RMS)})^2$ 

 $<sup>^{(3)}</sup>$  16.7 % x  $\pi$  x  $I_{AV}$  < I <  $\pi$  x  $I_{AV}$ 

 $<sup>^{(4)}</sup>$  l>  $\pi$  x l<sub>AV</sub>



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TRIGGERING						
PARAMETER	SYMBOL	TEST C	TEST CONDITIONS			
Maximum peak gate power	P <sub>GM</sub>			12	W	
Maximum average gate power	P <sub>G(AV)</sub>			3	VV	
Maximum peak gate current	I <sub>GM</sub>			3	Α	
Maximum peak negative gate voltage	- V <sub>GM</sub>			10		
		T <sub>J</sub> = - 40 °C	Anode supply = 6 V	4.0	V	
Maximum gate voltage required to trigger	$V_{GT}$	T <sub>J</sub> = 25 °C		2.5		
		T <sub>J</sub> = 125 °C	Tesistive load	1.7		
		T <sub>J</sub> = - 40 °C		270	mA	
Maximum gate current required to trigger	I <sub>GT</sub>	T <sub>J</sub> = 25 °C	Anode supply = 6 V resistive load	150		
		T <sub>J</sub> = 125 °C	Tesistive load	80		
Maximum gate voltage that will not trigger	$V_{GD}$	T <sub>J</sub> = 125 °C, rated V <sub>DR</sub>	0.25	V		
Maximum gate current that will not trigger	I <sub>GD</sub>	T <sub>J</sub> = 125 °C, rated V <sub>DRM</sub> applied 6			mA	

BLOCKING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum peak reverse and off-state leakage current at V <sub>RRM</sub> , V <sub>DRM</sub>	I <sub>RRM,</sub> I <sub>DRM</sub>	T <sub>J</sub> = 130 °C, gate open circuit	20	mA				
RMS insulation voltage	V <sub>INS</sub>	50 Hz, circuit to base, all terminals shorted	2500 (1 min) 3500 (1 s)	V				
Maximum critical rate of rise of off-state voltage	dV/dt (1)	$T_J$ = 130 °C, linear to 0.67 $V_{DRM}$ , gate open circuit	500	V/µs				

### Note

 $<sup>^{(1)}</sup>$  Available with dV/dt = 1000 V/ $\mu$ s, to complete code add S90 i.e. VSKT105/16S90P

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Junction operating temperature r	ange	$T_J$		- 40 to 130	°C		
Storage temperature range		$T_{Stg}$		- 40 to 150	O		
Maximum internal thermal resistance, junction to case per module		$R_{thJC}$	DC operation	0.135	K/W		
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface flat, smooth and greased	0.1	IV/VV		
Mounting torque + 10.9/	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3	5	Nm		
Mounting torque ± 10 % busbar			hours to allow for the spread of the compound.	3	INIII		
Approximate weight				110	g		
				4	OZ.		
Case style			JEDEC	TO-2	40AA		

△R CONDUCTION PER JUNCTION											
DEVICES		SINE HALF WAVE CONDUCTION						RECTANGULAR WAVE CONDUCTION			
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.105	0.04	0.05	0.05	0.08	0.12	0.03	0.05	0.06	0.08	0.12	°C/W

### Note

<sup>•</sup> Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

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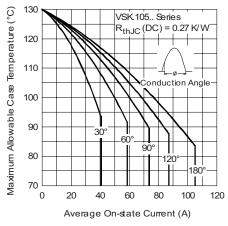


Fig. 1 - Current Ratings Characteristics

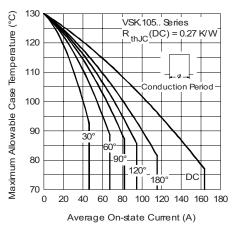


Fig. 2 - Current Ratings Characteristics

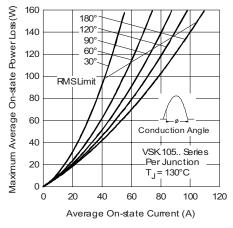


Fig. 3 - On-State Power Loss Characteristics

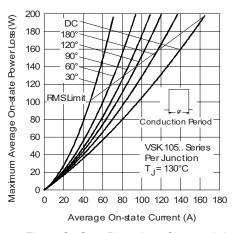


Fig. 4 - On-State Power Loss Characteristics

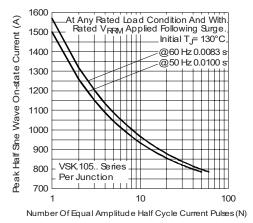


Fig. 5 - Maximum Non-Repetitive Surge Current

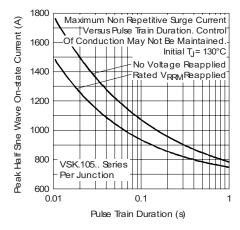


Fig. 6 - Maximum Non-Repetitive Surge Current



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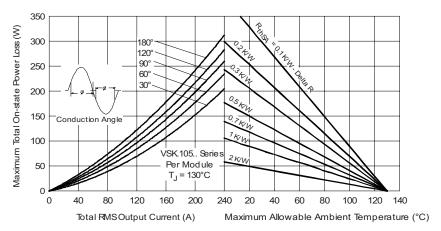


Fig. 7 - On-State Power Loss Characteristics

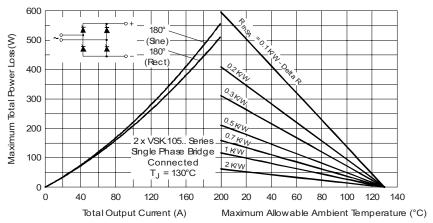


Fig. 8 - On-State Power Loss Characteristics

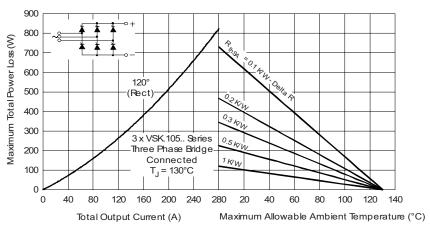


Fig. 9 - On-State Power Loss Characteristics

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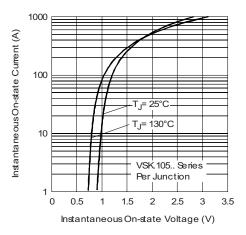


Fig. 10 - On-State Voltage Drop Characteristics

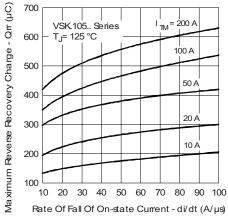


Fig. 11 - Recovery Charge Characteristics

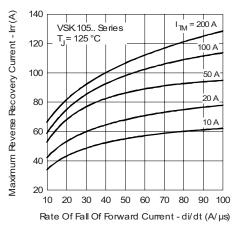


Fig. 12 - Recovery Current Characteristics

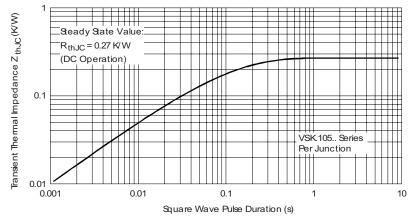


Fig. 13 - Thermal Impedance  $Z_{thJC}$  Characteristics



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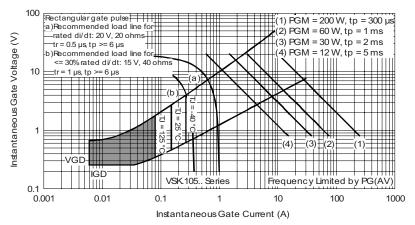
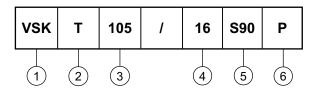


Fig. 14 - Gate Characteristics

### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Module type
- Circuit configuration (see end of datasheet)
- Current code (1)
- 4 Voltage code (see Voltage Ratings table)
- 5 dV/dt code: S90 = dV/dt 1000 V/µs No letter = dV/dt 500 V/µs
- 6 P = Lead (Pb)-free
- (1) Available with no auxiliary cathode (for details see dimensions - link at the end of datasheet)

To specify change: 105 to 106

e.g.: VSKT106/16P etc.

#### Note

• To order the optional hardware go to www.vishay.com/doc?95172

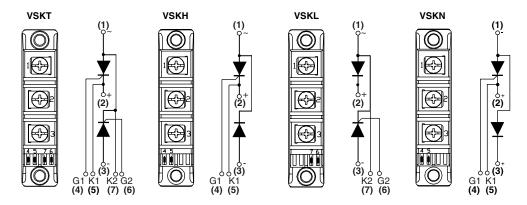
### VSK.105..PbF Series

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### **CIRCUIT CONFIGURATION**



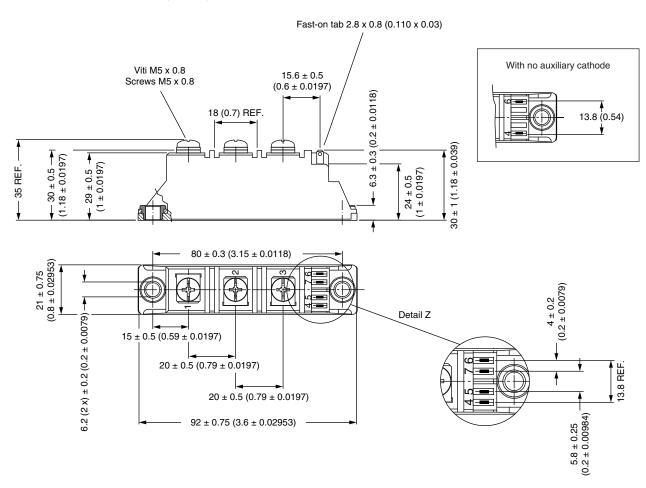
LINKS TO RELAT	TED DOCUMENTS
Dimensions	http://www.vishay.com/doc?95085



### Vishay Semiconductors

### **ADD-A-PAK SCR**

### **DIMENSIONS** in millimeters (inches)



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